

HD74LV126A

Quad. Bus Buffer Gates with 3-state Outputs

REJ03D0316-0300Z (Previous ADE-205-259A (Z)) Rev.3.00 Jun. 03, 2004

Description

The HD74LV126A features independent line drivers with three state outputs. Each output is disabled when the associated output enable (OE) input is low. To ensure the high impedance state during power up or power down, OE should be connected to GND through a pull-down resistor; the minimum value of the resistor is determined by the current souring capability of the driver. Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

Features

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V operation}$
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- All outputs V_0 (Max.) = 5.5 V (@ $V_{CC} = 0$ V)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.3 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Output current ± 8 mA (@V_{CC} = 3.0 V to 3.6 V), ± 16 mA (@V_{CC} = 4.5 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV126AFPEL	SOP-14 pin(JEITA)	FP-14DAV	FP	EL (2,000 pcs/reel)
HD74LV126ARPEL	SOP-14 pin(JEDEC)	FP-14DNV	RP	EL (2,500 pcs/reel)
HD74LV126ATELL	TSSOP-14 pin	TTP-14DV	Т	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

Function Table

Inputs

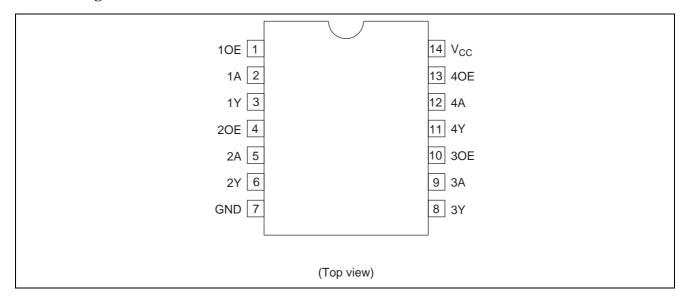
OE	Α	Output Y
Н	Н	Н
Н	L	L
L	X	Z

Note: H: High level

L: Low level X: Immaterial

Z: High impedance

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V _{CC}	-0.5 to 7.0	V	
Input voltage range*1	Vı	-0.5 to 7.0	V	
Output voltage range*1,2	Vo	-0.5 to V _{CC} + 0.5	V	Output: H or L
		-0.5 to 7.0		V _{CC} : OFF or Output: Z
Input clamp current	I _{IK}	-20	mA	V _I < 0
Output clamp current	lok	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	lo	±35	mA	$V_O = 0$ to V_{CC}
Continuous current through	I _{CC} or I _{GND}	±70	mA	
V _{CC} or GND				
Maximum power dissipation at	P _T	785	mW	SOP
Ta = 25° C (in still air)* ³		500		TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

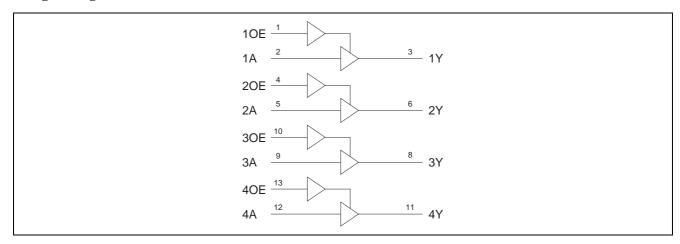
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	Vcc	2.0	5.5	V	
Input voltage range	Vı	0	5.5	V	
Output voltage range	Vo	0	V _{CC}	V	H or L
		0	5.5		High impedance state
Output current	I _{OH}	_	-50	μΑ	V _{CC} = 2.0 V
		_	-2	mA	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	-8		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	-16		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
	I _{OL}	_	50	μΑ	V _{CC} = 2.0 V
		_	2	mA	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	8		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	16		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Input transition rise or fall rate	Δt /Δν	0	200	ns/V	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		0	100		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		0	20		V _{CC} = 4.5 to 5.5 V
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Logic Diagram



DC Electrical Characteristics

 $Ta = -40 \text{ to } 85^{\circ}\text{C}$

Item	Symbol	V _{CC} (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.0	1.5	_	_	V	
		2.3 to 2.7	$V_{CC} \times 0.7$	_	_		
		3.0 to 3.6	$V_{CC} \times 0.7$	_	_		
		4.5 to 5.5	$V_{CC} \times 0.7$	_	_		
	V _{IL}	2.0	_	_	0.5		
		2.3 to 2.7	_	_	$V_{\text{CC}} \times 0.3$		
		3.0 to 3.6	_	_	$V_{\text{CC}} \times 0.3$		
		4.5 to 5.5	_	_	$V_{\text{CC}}\!\times\!0.3$		
Output voltage	V_{OH}	Min to Max	V _{CC} - 0.1	_	_	V	$I_{OH} = -50 \mu A$
		2.3	2.0	_	_		$I_{OH} = -2 \text{ mA}$
		3.0	2.48	_	_		$I_{OH} = -8 \text{ mA}$
		4.5	3.8	_	_		$I_{OH} = -16 \text{ mA}$
	V _{OL}	Min to Max	_	_	0.1		I _{OL} = 50 μA
		2.3	_	_	0.4		I _{OL} = 2 mA
		3.0	_	_	0.44		I _{OL} = 8 mA
		4.5	_	_	0.55		I _{OL} = 16 mA
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	$V_I = 5.5 \text{ V or GND}$
Off-state output current	l _{OZ}	5.5	_	_	±5	μΑ	$V_O = V_{CC}$ or GND
Quiescent supply current	I _{CC}	5.5	_	_	20	μΑ	$V_I = V_{CC}$ or GND, $I_O = 0$
Output leakage current	I _{OFF}	0	_	_	5	μΑ	V_1 or $V_0 = 0$ V to 5.5 V
Input capacitance	C _{IN}	3.3	_	3	_	pF	$V_I = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

 $V_{CC}=2.5\pm0.2~V$

		Ta =	25°C		Ta = -4	40 to 85°C		Test	FROM	TO
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	7.1	13.0	1.0	15.5	ns	C _L = 15 pF	Α	Υ
delay time	t_{PHL}	_	9.2	16.5	1.0	18.5		C _L = 50 pF		
Enable time	t _{ZH}	_	7.4	13.0	1.0	15.5	ns	C _L = 15 pF	OE	Υ
	t_{ZL}	_	9.5	16.5	1.0	18.5		C _L = 50 pF		
Disable time	t _{HZ}	_	5.7	14.7	1.0	17.0	ns	C _L = 15 pF	OE	Υ
	t_{LZ}	_	8.1	18.2	1.0	20.5		C _L = 50 pF		

 $V_{CC} = 3.3 \pm 0.3 \ V$

		Ta =	25°C		Ta = -4	0 to 85°C		Test	FROM	то
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	5.0	8.0	1.0	9.5	ns	C _L = 15 pF	Α	Υ
delay time	t_{PHL}	_	6.4	11.5	1.0	13.0		C _L = 50 pF		
Enable time	t _{ZH}	_	5.1	8.0	1.0	9.5	ns	C _L = 15 pF	OE	Υ
	t_{ZL}	_	6.6	11.5	1.0	13.0		C _L = 50 pF		
Disable time	t _{HZ}	_	4.4	9.7	1.0	11.5	ns	C _L = 15 pF	OE	Υ
	t_{LZ}	_	6.1	13.2	1.0	15.0		C _L = 50 pF		

 $V_{CC} = 5.0 \pm 0.5 \ V$

		Ta =	25°C		Ta = -4	40 to 85°C		Test	FROM	то
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	3.5	5.5	1.0	6.5	ns	C _L = 15 pF	Α	Υ
delay time	t_{PHL}	_	4.6	7.5	1.0	8.5		C _L = 50 pF	<u></u>	
Enable time	t _{ZH}	_	3.6	5.1	1.0	6.0	ns	C _L = 15 pF	OE	Υ
	t_{ZL}	_	4.6	7.1	1.0	8.0	_	C _L = 50 pF		
Disable time	t _{HZ}	_	3.3	6.8	1.0	8.0	ns	C _L = 15 pF	OE	Υ
	t_{LZ}	_	4.3	8.8	1.0	10.0	_	C _L = 50 pF		

Output-skew Characteristics

			Ta = 25°	С	Ta = -40	Ta = -40 to 85°C		
Item	Symbol	$V_{CC} = (V)$	Min	Max	Min	Max	Unit	
Output skew	t _{sk (O)}	2.3 to 2.7	_	2.0	_	2.0	ns	
		3.0 to 3.6	_	1.5	_	1.5		
		4.5 to 5.5	_	1.0	_	1.0		

Note: Skew between any outputs of the same package switching in the same direction. This parameter is warranted but not production tested.

Operating Characteristics

 $C_L = 50 pF$

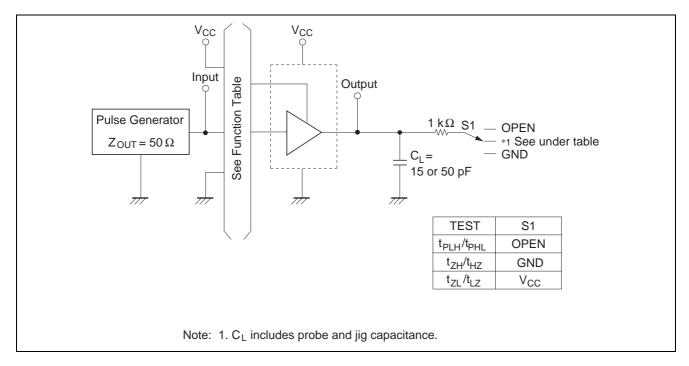
			Ta = 2	5°C			
Item	Symbol	$V_{CC} = (V)$	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance	C_{PD}	3.3	_	14.4	_	pF	f = 10 MHz
		5.0	_	15.9	_		

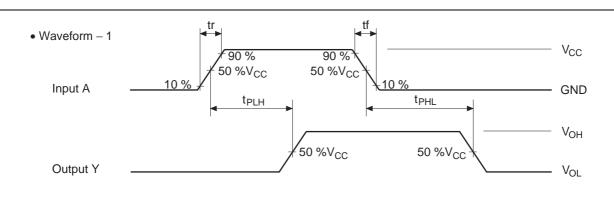
Noise Characteristics

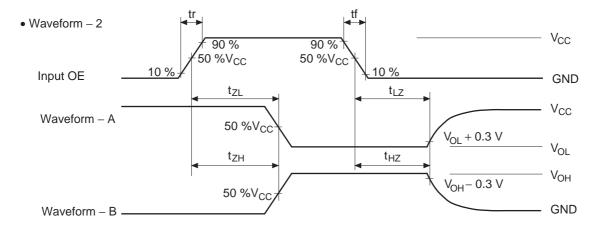
 $C_L = 50 pF$

			Ta = 25°C				
Item	Symbol	$V_{CC} = (V)$	Min	Тур	Max	Unit	Test Conditions
Quiet output, maximum dynamic V _{OL}	V _{OL (P)}	3.3	_	0.3	0.8	V	
Quiet output, minimum dynamic V _{OL}	V _{OL (V)}	3.3	_	-0.2	-0.8	V	
Quiet output, minimum dynamic V _{OH}	$V_{OH\ (V)}$	3.3	_	3.1	_	V	
High-level dynamic input voltage	$V_{\text{IH (D)}}$	3.3	2.31	_	_	V	
Low-level dynamic input voltage	$V_{IL\;(D)}$	3.3	_	_	0.99	V	

Test Circuit



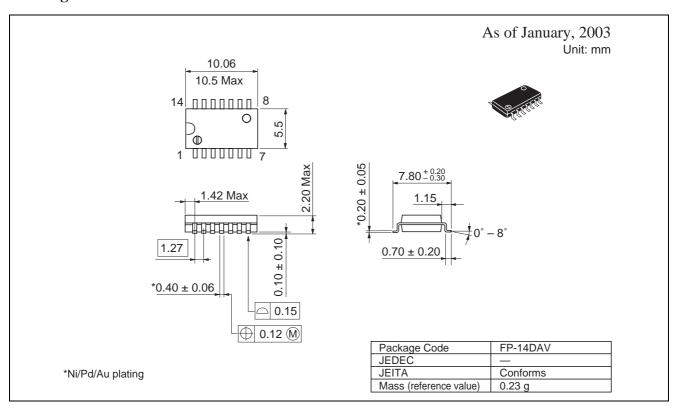


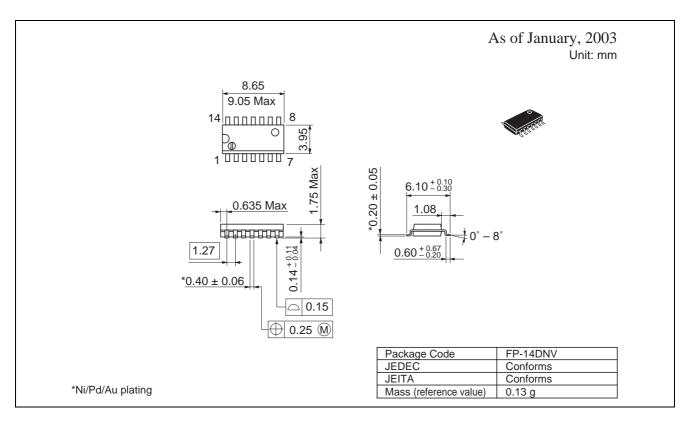


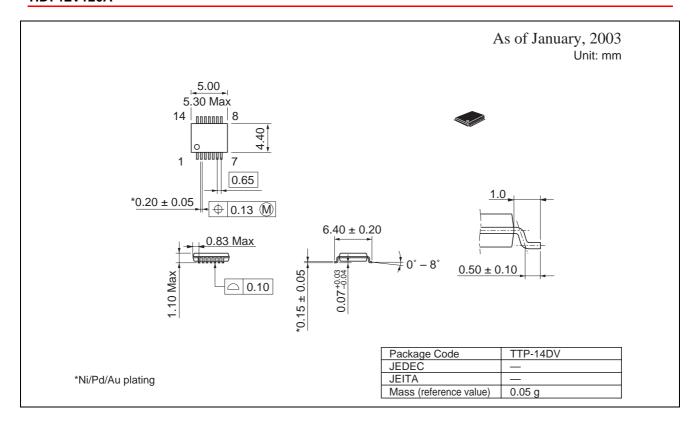
Notes: 1. $t_r \le 3$ ns, $t_f \le 3$ ns

- 2. Input waveform: PRR ≤ 1 MHz, duty cycle 50%
- 3. Waveform–A is for an output with internal conditions such that the output is low except when disabled by the output control.
- 4. Waveform–B is for an output with internal conditions such that the output is high except when disabled by the output control.

Package Dimensions







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